XN0111F (XN111F)

Silicon PNP epitaxial planer transistor

For switching/digital circuits

Features

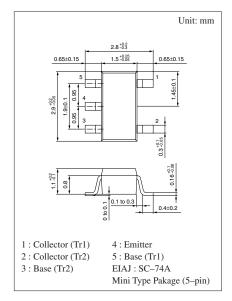
- Two elements incorporated into one package. (Emitter-coupled transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half.

Basic Part Number of Element

• UNR111F(UN111F) \times 2 elements

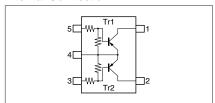
Absolute Maximum Ratings (Ta=25°C)

| Parameter | | Symbol | Ratings | Unit | |
|-------------------|------------------------------|------------------|-------------|------|--|
| Rating of element | Collector to base voltage | V_{CBO} | -50 | V | |
| | Collector to emitter voltage | V _{CEO} | -50 | V | |
| | Collector current | I_{C} | -100 | mA | |
| Overall | Total power dissipation | P_{T} | 300 | mW | |
| | Junction temperature | T_{j} | 150 | °C | |
| | Storage temperature | T_{stg} | -55 to +150 | °C | |



Marking Symbol: 70

Internal Connection

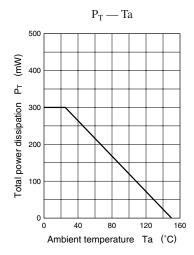


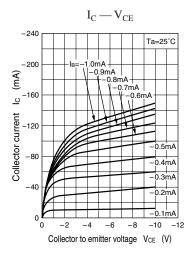
Electrical Characteristics (Ta=25°C)

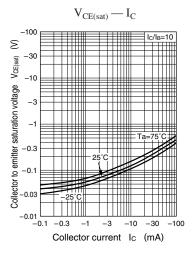
| Parameter | Symbol | Conditions | min | typ | max | Unit |
|--|---------------------------------|--|------|------|--------|------|
| Collector to base voltage | V _{CBO} | $I_{\rm C} = -10\mu A, I_{\rm E} = 0$ | -50 | | | V |
| Collector to emitter voltage | V _{CEO} | $I_C = -2mA, I_B = 0$ | -50 | | | V |
| Collector cutoff current | I_{CBO} | $V_{CB} = -50V, I_E = 0$ | | | - 0.1 | μА |
| Conector cuton current | I_{CEO} | $V_{CE} = -50V, I_{B} = 0$ | | | - 0.5 | μΑ |
| Emitter cutoff current | I_{EBO} | $V_{EB} = -6V, I_C = 0$ | | | - 1.0 | mA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = -10V, I_{C} = -5mA$ | 30 | | | |
| Forward current transfer h _{FE} ratio | h _{FE} (small/large)*1 | $V_{CE} = -10V, I_{C} = -5mA$ | 0.5 | 0.99 | | |
| Collector to emitter saturation voltage | V _{CE(sat)} | $I_C = -10 \text{mA}, I_B = -0.3 \text{mA}$ | | | - 0.25 | V |
| Output voltage high level | V _{OH} | $V_{CC} = -5V, V_B = -0.5V, R_L = 1k\Omega$ | -4.9 | | | V |
| Output voltage low level | V _{OL} | $V_{CC} = -5V, V_B = -2.5V, R_L = 1k\Omega$ | | | - 0.2 | V |
| Transition frequency | f_T | $V_{CB} = -10V$, $I_E = 1mA$, $f = 200MHz$ | | 80 | | MHz |
| Input resistance | R ₁ | | -30% | 4.7 | +30% | kΩ |
| Resistance ratio | R ₁ /R ₂ | | | 0.47 | | |

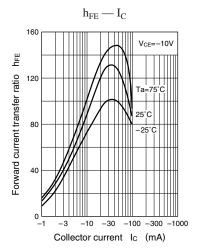
^{*1} Ratio between 2 elements

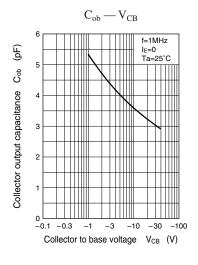
Note.) The Part number in the Parenthesis shows conventional part number.

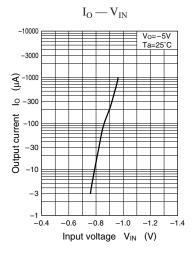


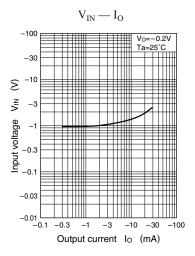












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